2N5038

NPN Silicon Transistors

Fast switching speeds and high current capacity ideally suit these parts for use in switching regulators, inverters, wide-band amplifiers and power oscillators in industrial and commercial applications.

Features

- High Speed $t_f = 0.5 \mu s$ (Max)
- High Current $I_{C(max)} = 30 \text{ Amps}$
- Low Saturation $V_{CE(sat)} = 2.5 \text{ V (Max)} @ I_C = 20 \text{ Amps}$
- Pb-Free Package is Available*

MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	90	Vdc
Collector-Base Voltage	V _{CBO}	150	Vdc
Collector-Emitter Voltage	V _{CEV}	150	Vdc
Emitter-Base Voltage	V _{EBO}	7	Vdc
Collector Current - Continuous Peak (Note 2)	I _C I _{CM}	20 30	Adc
Base Current - Continuous	Ι _Β	5	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	140 0.8	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +200	°C

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.25	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Indicates JEDEC Registered Data.
- 2. Pulse Test: Pulse Width \leq 10 ms, Duty Cycle \leq 50%.

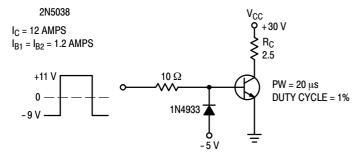


Figure 1. Switching Time Test Circuit



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20 AMPERE NPN SILICON POWER TRANSISTORS 90 VOLTS - 140 WATTS



TO-204AA (TO-3) CASE 1-07 STYLE 1

MARKING DIAGRAMS



G = Pb-Free Package A = Assembly Location

YY = Year WW = Work Week MEX = Country of Origin

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted) (Note 3)

	Symbol	Min	Max	Unit	
OFF CHARACTE	RISTICS				
Collector-Emitter Sustaining Voltage (Note 4) $(I_C = 200 \text{ mAdc}, I_B = 0)$		V _{CEO(sus)}	90	-	Vdc
Collector Cutoff Current (V _{CE} = 140 Vdc, V _{BE(off)} = 1.5 V) (V _{CE} = 100 Vdc, V _{BE(off)} = 1.5 Vdc, T _C = 150 $^{\circ}$ C)		I _{CEX}	- -	50 10	mAdc
Emitter Cutoff Current $(V_{EB} = 5 \text{ Vdc}, I_{C} = 0)$ $(V_{EB} = 7 \text{ Vdc}, I_{C} = 0)$		I _{EBO}	- -	5 50	mAdc
ON CHARACTER	HISTICS (Note 4)				•
DC Current Gain (I _C = 12 Adc, V _{CE} = 5 Vdc)		h _{FE}	20	100	-
Collector–Emitter Saturation Voltage (I _C = 20 Adc, I _B = 5 Adc)		V _{CE(sat)}	-	2.5	Vdc
Base–Emitter Saturation Voltage (I _C = 20 Adc, I _B = 5 Adc)		V _{BE(sat)}	-	3.3	Vdc
DYNAMIC CHAR	ACTERISTICS		•	•	•
Magnitude of Common–Emitter Small–Signal Short–Circuit Forward Current Transfer Ratio ($I_C = 2$ Adc, $V_{CE} = 10$ Vdc, $f = 5$ MHz)		h _{fe}	12	-	-
SWITCHING CHA	RACTERISTICS		•	•	•
RESISTIVE LOA	D				
Rise Time	(V _{CC} = 30 Vdc)	t _r	-	0.5	μS
Storage Time	(I _C = 12 Adc, I _{B1} = I _{B2} = 1.2 Adc)	t _s	_	1.5	μS

^{3.} Indicates JEDEC Registered Data.

ORDERING INFORMATION

Device	Package	Shipping	
2N5038	TO-204		
2N5038G	TO-204 (Pb-Free)	100 Units / Tray	

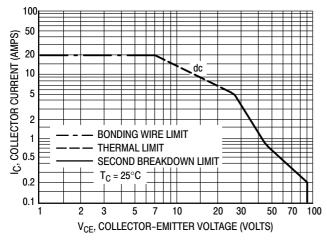


Figure 2. Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

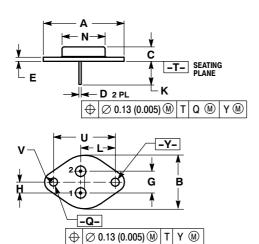
Second breakdown pulse limits are valid for duty cycles to 10%. At high case temperatures, thermal limitations may reduce the power that can be handled to values less than the limitations imposed by second breakdown.

^{4.} Pulse Test: Pulse Width \leq 300, μ s, Duty Cycle \leq 2%.

2N5038

PACKAGE DIMENSIONS

CASE 1-07 TO-204AA (TO-3) ISSUE Z



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTRIOLLING DIMENSION: INCH.
 3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	1.550 REF		39.37 REF	
В		1.050		26.67
С	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
Е	0.055	0.070	1.40	1.77
G	0.430 BSC		10.92 BSC	
Н	0.215 BSC		5.46 BSC	
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
N		0.830		21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15 BSC	
٧	0.131	0.188	3.33	4.77

STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR